# NSN 5962-01-086-0289

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#### **Body Length:**

Between 1.188 inches and 1.212 inches

#### **Body Width:**

Between 0.565 inches and 0.590 inches

## **Body Height:**

Between 0.110 inches and 0.160 inches

#### **Maximum Power Dissipation Rating:**

650.0 milliwatts

#### **Operating Tempurature Range:**

-55.0/+125.0 degrees celsius

#### Storage Tempurature Range:

-65.0/+150.0 degrees celsius

#### End Application:

Control-indicator assembly, type c-1040 (v) /g

#### **Features Provided:**

Hermetically sealed and monolithic and positive outputs and programmable and programmed

#### **Inclosure Material:**

Ceramic and glass

## Inclosure Configuration:

Dual-in-line

#### **Output Logic Form:**

Transistor-transistor logic

#### Input Circuit Pattern:

13 input

#### **Terminal Surface Treatment:**

Solder

#### Voltage Rating And Type Per Characteristic:

5.5 volts power source

#### **Time Rating Per Chacteristic:**

70.00 nanoseconds propagation delay time, low to high level output and 70.00 nanoseconds propagation delay time, high to low level output

## Memory Device Type:

Rom

## Memory Capacity:

Unknown

## Test Data Document:

50464-7611891 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.;

excludes any specification, standard or other document that may be referenced in a basic governing drawing)

## Terminal Type And Quantity:

24 printed circuit

## Shelf Life:

N/a

## Unit Of Measure:

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## Demilitarization:

Yes - demil/mli

Fiig:

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